## NSN 5961-00-453-8658

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View Online at https://aerobasegroup.com/nsn/5961-00-453-8658 **Inclosure Material:** Metal **Function For Which Designed:** Reverse blocking **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 30.94 millimeters and 31.75 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage and 400.0 repetitive peak reverse voltage and 500.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 235.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector universal and 400.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 1 threaded stud and 3 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0